
2SJ505(L), 2SJ505(S)

Silicon P Channel MOS FET
High Speed Power Switching

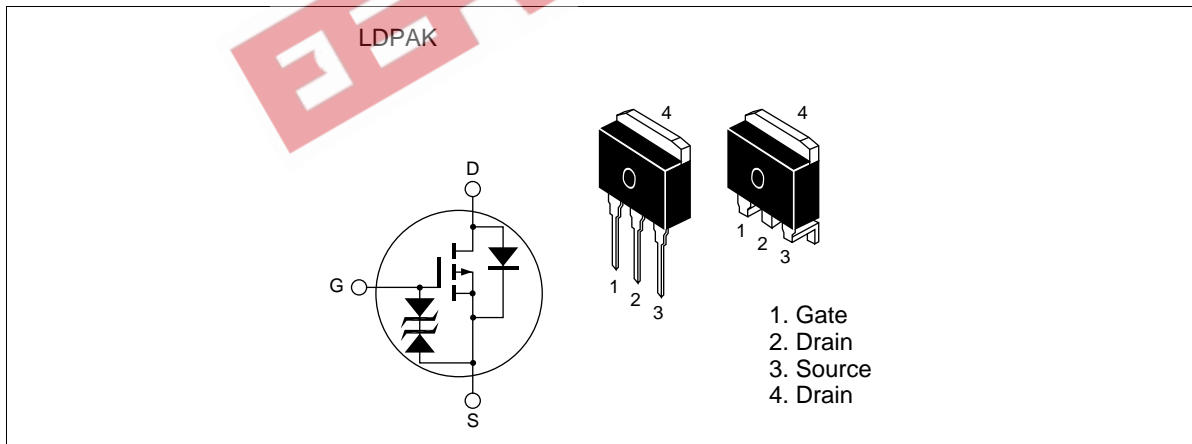
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ADE-208-547
Target specification 1st. Edition

Features

- Low on-resistance
 $R_{DS(on)} = 0.017\Omega$ typ.
- Low drive current.
- 4V gate drive devices.
- High speed switching.

Outline



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Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	-60	V
Gate to source voltage	V_{GSS}	±20	V
Drain current	I_D	-50	A
Drain peak current	$I_{D(pulse)}^{*1}$	-200	A
Body to drain diode reverse drain current	I_{DR}	-50	A
Avalanche current	I_{AP}^{*3}	-50	A
Avalanche energy	E_{AR}^{*3}	214	mJ
Channel dissipation	Pch^{*2}	75	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

- Notes: 1. $PW \leq 10\mu s$, duty cycle $\leq 1\%$
2. Value at $Tc = 25^\circ C$
3. Value at $Ta = 25^\circ C$, $Rg \geq 50 \Omega$, $L=100\mu H$

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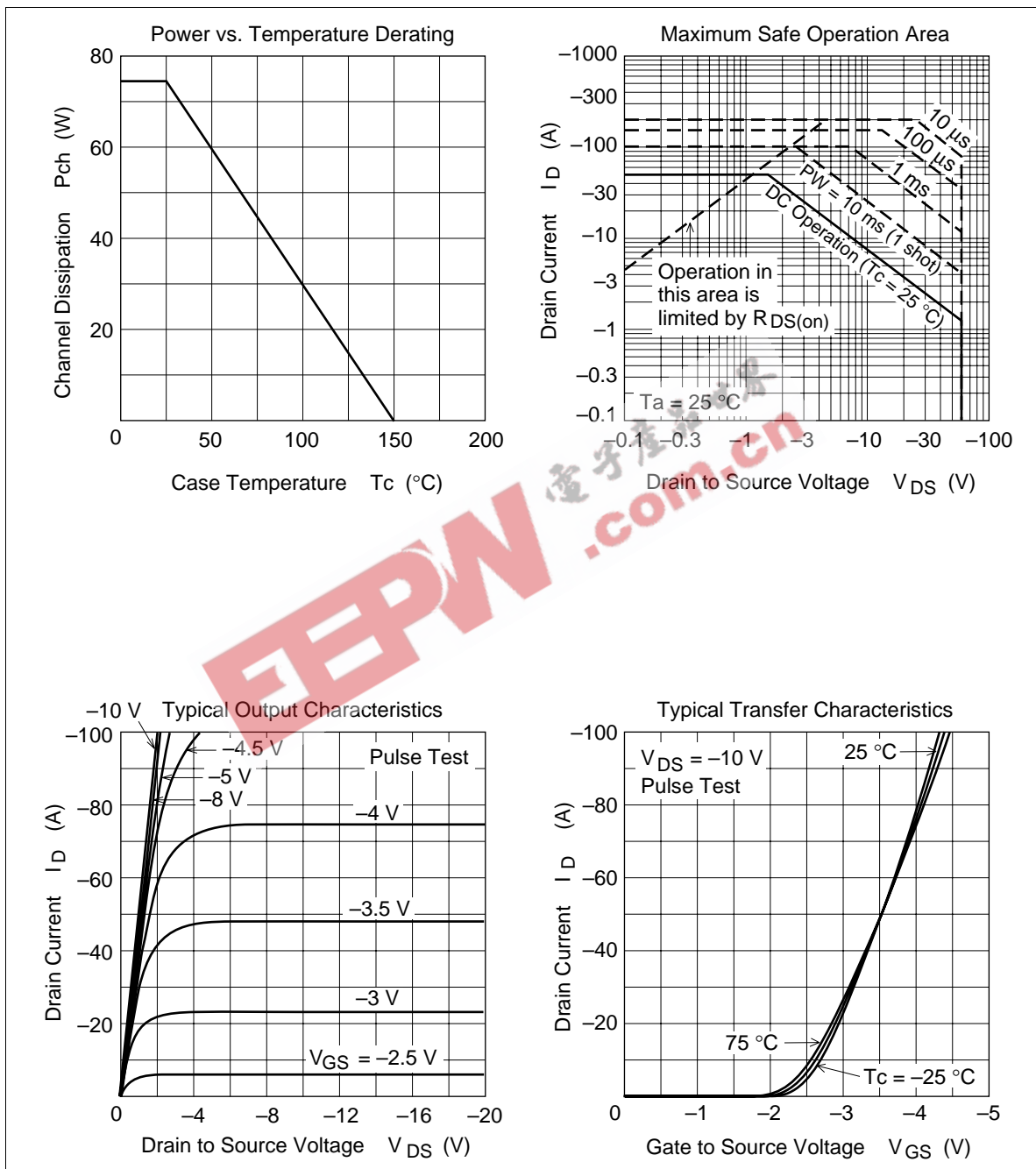
Electrical Characteristics (T_a = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	-60	—	—	V	$I_D = -10\text{mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	—	—	V	$I_G = \pm 100\mu\text{A}, V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	-10	μA	$V_{DS} = -60\text{V}, V_{GS} = 0$
Gate to source leak current	I_{GSS}	—	—	±10	μA	$V_{GS} = \pm 16\text{V}, V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-1.0	—	-2.0	V	$I_D = -1\text{mA}, V_{DS} = -10\text{V}$
Static drain to source on state resistance	$R_{DS(on)}$	—	0.017	0.022	Ω	$I_D = -25\text{A}, V_{GS} = -10\text{V}^{*1}$
	$R_{DS(on)}$	—	0.024	0.036	Ω	$I_D = -25\text{A}, V_{GS} = -4\text{V}^{*1}$
Forward transfer admittance	$ y_{fs} $	27	39	—	S	$I_D = 25\text{A}, V_{DS} = 10\text{V}^{*1}$
Input capacitance	C_{iss}	—	4100	—	pF	$V_{DS} = -10\text{V}$
Output capacitance	C_{oss}	—	2100	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	C_{rss}	—	450	—	pF	$f = 1\text{MHz}$
Turn-on delay time	$t_{d(on)}$	—	32	—	ns	$V_{GS} = -10\text{V}, I_D = -10\text{A}$
Rise time	t_r	—	225	—	ns	$R_L = 3\Omega$
Turn-off delay time	$t_{d(off)}$	—	530	—	ns	
Fall time	t_f	—	330	—	ns	
Body to drain diode forward voltage	V_{DF}	—	-1.1	—	V	$I_F = -50\text{A}, V_{GS} = 0$
Body to drain diode reverse recovery time	t_{rr}	—	110	—	ns	$I_F = -50\text{A}, V_{GS} = 0$ $di_F/dt = 50\text{A}/\mu\text{s}$

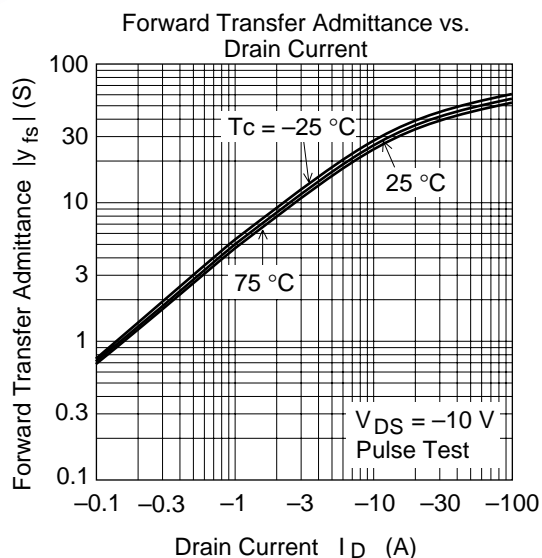
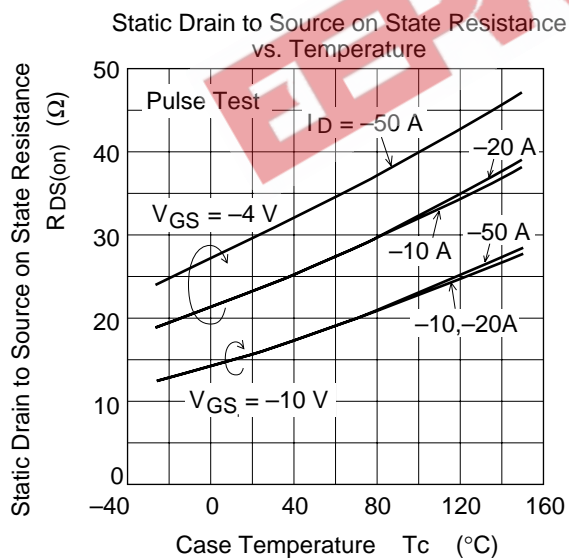
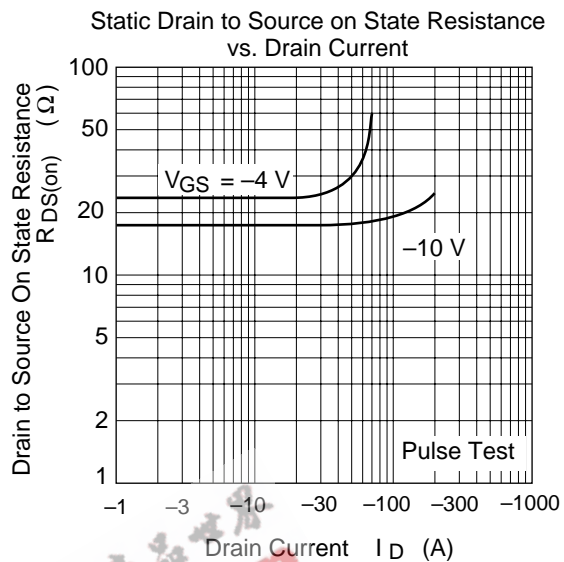
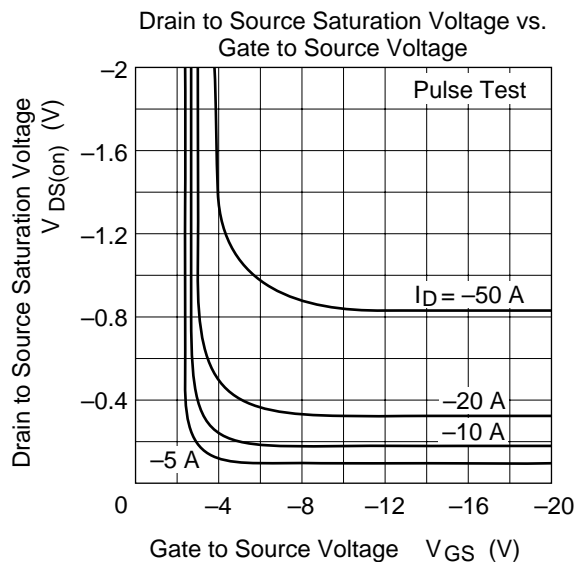
Note: 1. Pulse test

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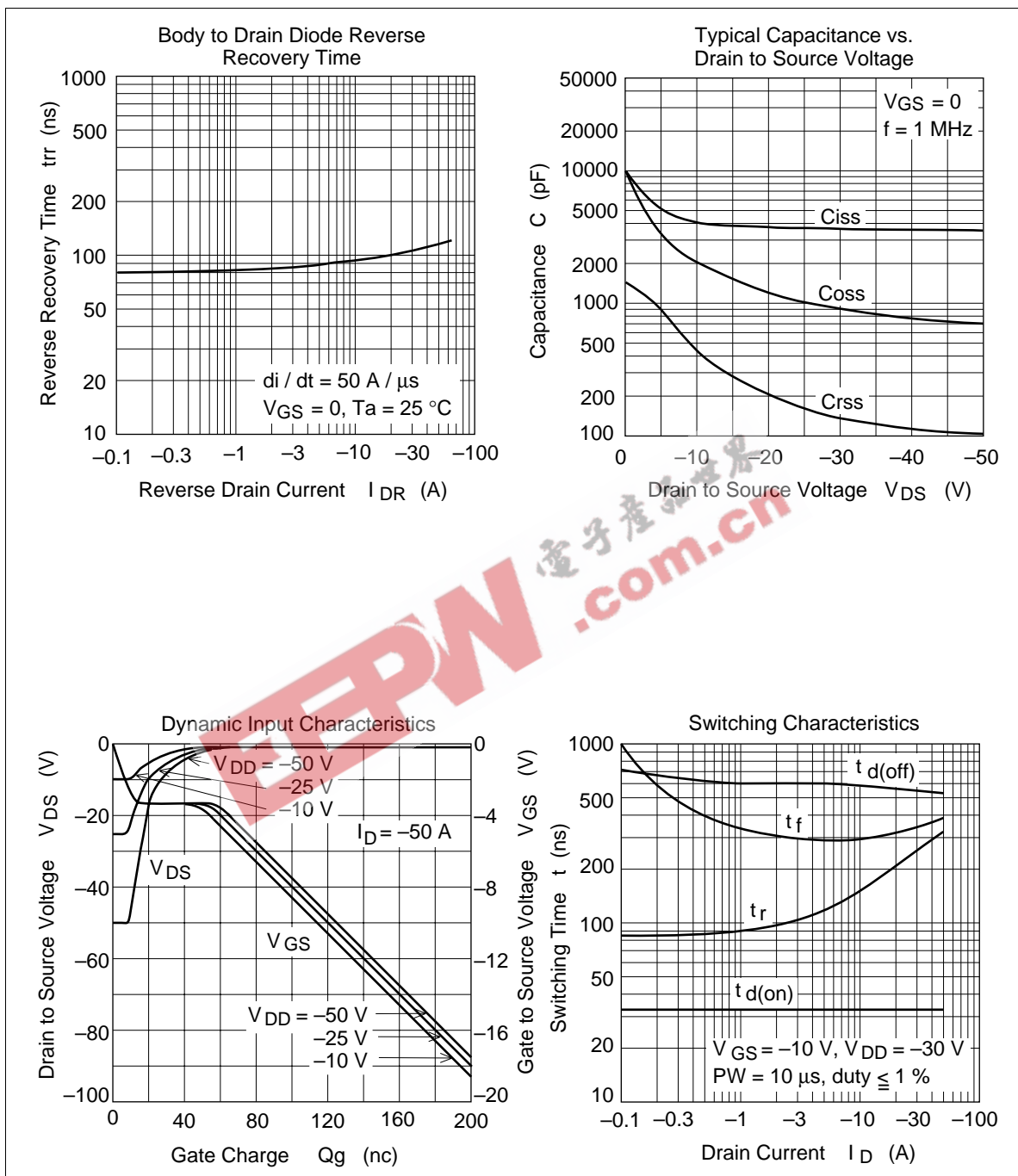
Main Characteristics



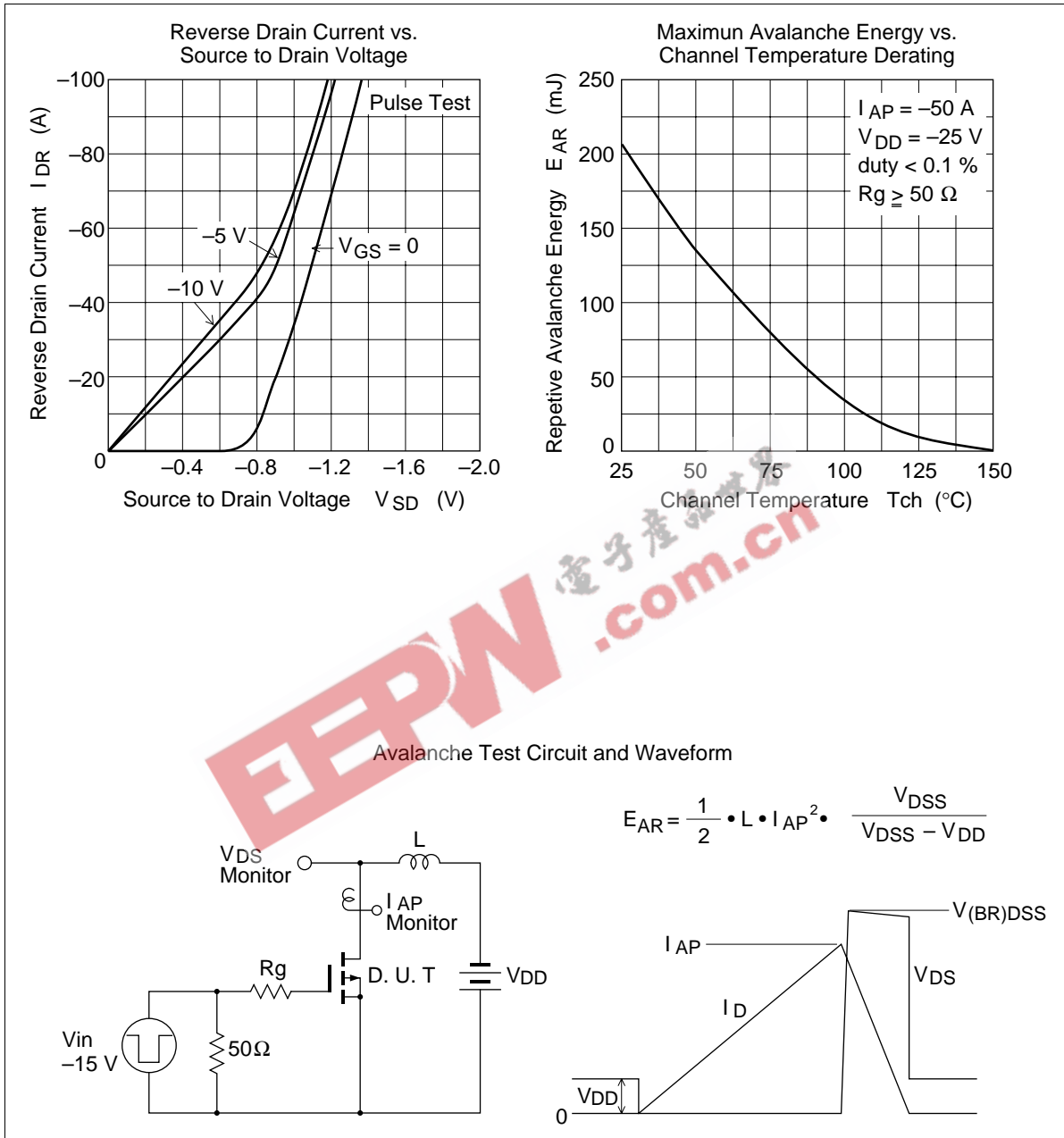
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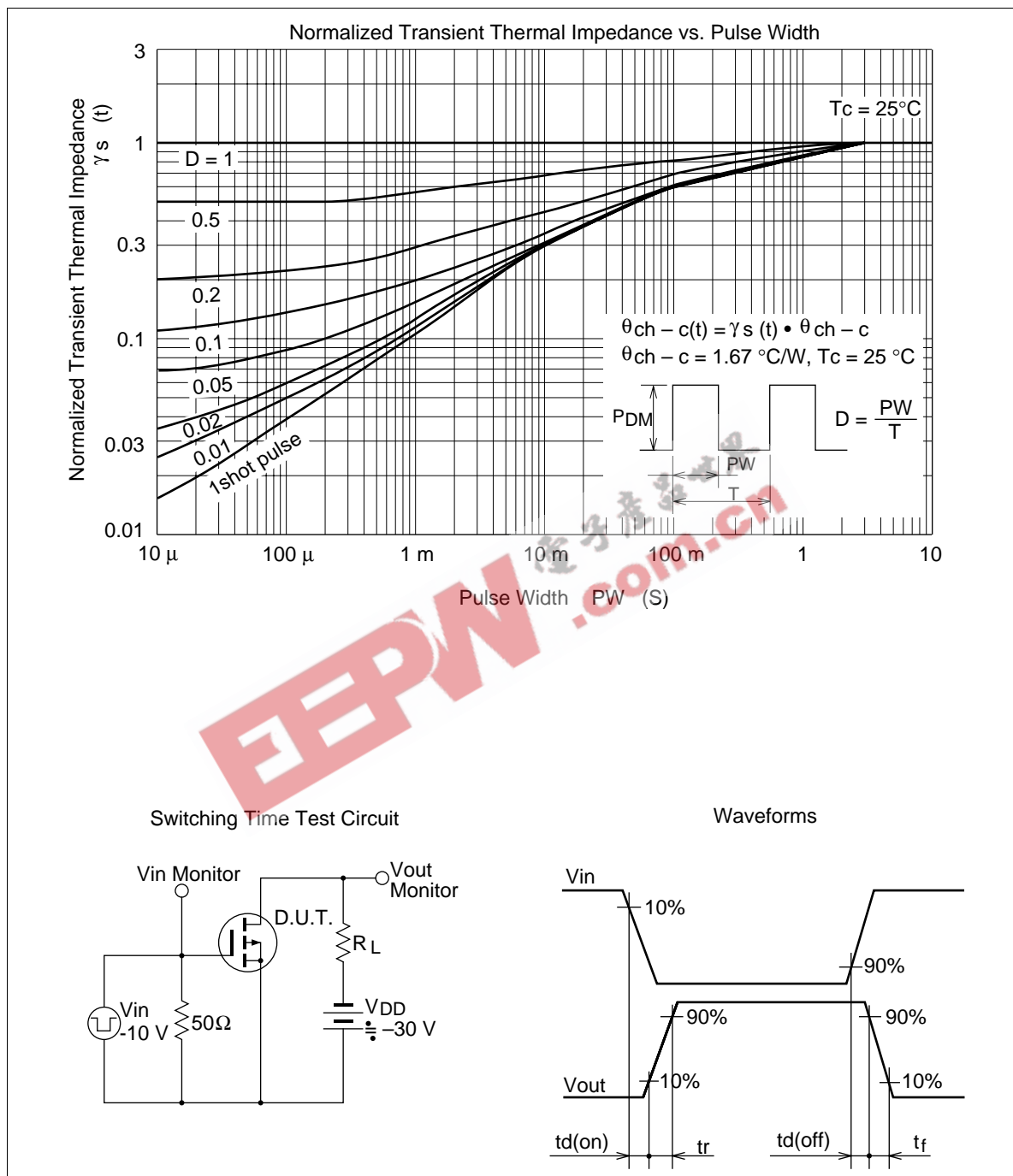
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